- 12 A Continuous On-State Current
- 100 A Surge-Current
- Glass Passivated Wafer
- 400 V to 800 V Off-State Voltage
- Max I<sub>GT</sub> of 20 mA

# TO-220 PACKAGE (TOP VIEW) K 1 A 2 G 3

Pin 2 is in electrical contact with the mounting base.

MDC1ACA

### absolute maximum ratings over operating case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT	
	TIC126D		400		
Repetitive peak off-state voltage	TIC126M	V	600	V	
	TIC126S	$V_{DRM}$	700		
	TIC126N		800		
Repetitive peak reverse voltage	TIC126D		400	V	
	TIC126M	V	600		
	TIC126S	$V_{RRM}$	700		
	TIC126N		800		
Continuous on-state current at (or below) 70°C case temperature (see Note 1)			12	Α	
Average on-state current (180° conduction angle) at (or below) 70°C case temperature		ı	7.5	А	
(see Note 2)		I <sub>T(AV)</sub>	7.5		
Surge on-state current at (or below) 25°C case temperature (see Note 3)		I <sub>TM</sub>	100	Α	
Peak positive gate current (pulse width ≤ 300 μs)		I <sub>GM</sub>	3	Α	
Peak gate power dissipation (pulse width ≤ 300 μs)		$P_{GM}$	5	W	
Average gate power dissipation (see Note 4)		$P_{G(AV)}$	1	W	
Operating case temperature range		T <sub>C</sub>	-40 to +110	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +125	°C	
Lead temperature 1.6 mm from case for 10 seconds		T <sub>L</sub>	230	°C	

NOTES: 1. These values apply for continuous dc operation with resistive load. Above 70°C derate linearly to zero at 110°C.

- 2. This value may be applied continuously under single phase 50 Hz half-sine-wave operation with resistive load. Above 70°C derate linearly to zero at 110°C.
- 3. This value applies for one 50 Hz half-sine-wave when the device is operating at (or below) the rated value of peak reverse voltage and on-state current. Surge may be repeated after the device has returned to original thermal equilibrium.
- 4. This value applies for a maximum averaging time of 20 ms.



### electrical characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER		TEST CONDITION	ONS	MIN	TYP	MAX	UNIT
I <sub>DRM</sub>	Repetitive peak off-state current	V <sub>D</sub> = rated V <sub>DRM</sub>		T <sub>C</sub> = 110°C			2	mA
I <sub>RRM</sub>	Repetitive peak reverse current	V <sub>R</sub> = rated V <sub>RRM</sub>	I <sub>G</sub> = 0	T <sub>C</sub> = 110°C			2	mA
I <sub>GT</sub>	Gate trigger current	V <sub>AA</sub> = 12 V	$R_L = 100 \Omega$	t <sub>p(g)</sub> ≥ 20 μs		8	20	mA
V <sub>GT</sub> Gate trigger voltage	$V_{AA} = 12 \text{ V}$ $t_{p(g)} \ge 20  \mu\text{s}$	$R_L = 100 \Omega$	$T_C = -40^{\circ}C$			2.5		
	Gate trigger voltage	$V_{AA} = 12 \text{ V}$ $t_{p(g)} \ge 20  \mu\text{s}$	$R_L = 100 \Omega$			0.8	1.5	V
		$V_{AA} = 12 \text{ V}$ $t_{p(g)} \ge 20  \mu\text{s}$	$R_L = 100 \Omega$	T <sub>C</sub> = 110°C	0.2			
I <sub>H</sub> Holding current	$V_{AA} = 12 \text{ V}$ Initiating $I_T = 100 \text{ mA}$		T <sub>C</sub> = - 40°C			100	mA	
	Troiding durions	$V_{AA} = 12 \text{ V}$ Initiating $I_T = 100 \text{ mA}$					40	
V <sub>T</sub>	On-state voltage	I <sub>T</sub> = 12 A	(see Note 5)				1.4	V
dv/dt	Critical rate of rise of off-state voltage	V <sub>D</sub> = rated V <sub>D</sub>	I <sub>G</sub> = 0	T <sub>C</sub> = 110°C		400		V/µs

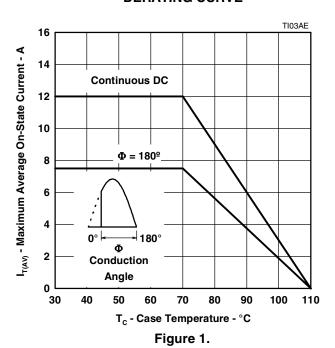
NOTE 5: This parameter must be measured using pulse techniques,  $t_p = 300 \mu s$ , duty cycle  $\leq 2 \%$ . Voltage sensing-contacts, separate from the current carrying contacts, are located within 3.2 mm from the device body.

### thermal characteristics

	PARAMETER		TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			2.4	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

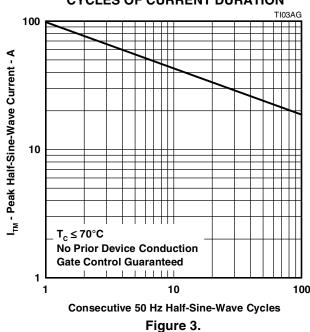
### THERMAL INFORMATION

## **AVERAGE ON-STATE CURRENT DERATING CURVE**

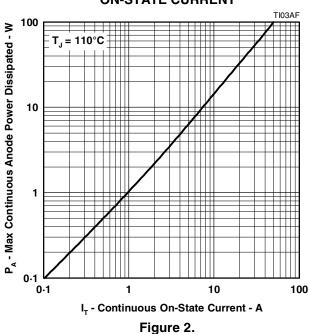


# **SURGE ON-STATE CURRENT**

### **CYCLES OF CURRENT DURATION**

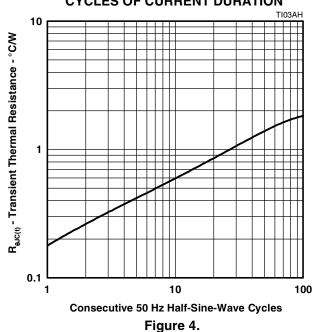


# **MAX ANODE POWER LOSS ON-STATE CURRENT**



# TRANSIENT THERMAL RESISTANCE

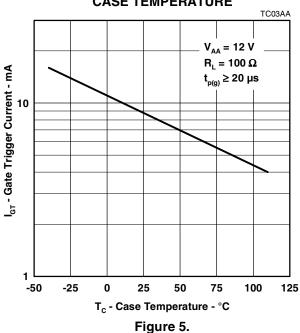
### **CYCLES OF CURRENT DURATION**



### TYPICAL CHARACTERISTICS

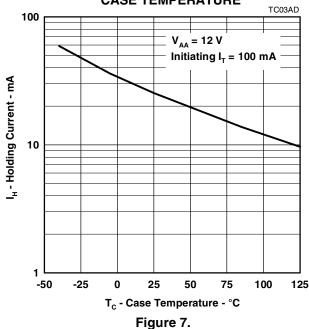
### **GATE TRIGGER CURRENT** vs

### **CASE TEMPERATURE**

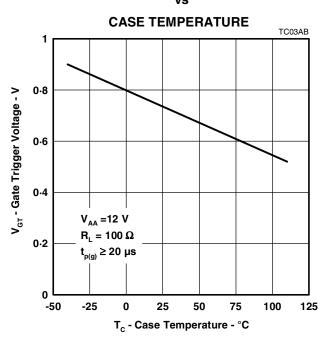


### **HOLDING CURRENT** vs

### **CASE TEMPERATURE**



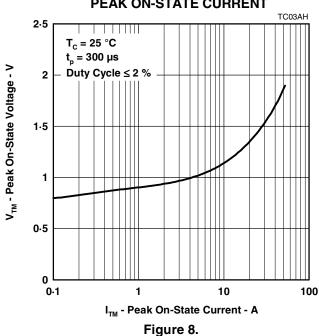
# **GATE TRIGGER VOLTAGE**



# **PEAK ON-STATE VOLTAGE**

Figure 6.

### **PEAK ON-STATE CURRENT**



### PRODUCT INFORMATION